TOSHIBA Field-Effect Transistor Silicon N Channel MOS Type

SSM3K36FS

○ High-Speed Switching Applications

1.5-V drive
 Low ON-resistance : R_{on} = 1.52 Ω (max) (@V_{GS} = 1.5 V)

: $R_{OR} = 1.32 \Omega \text{ (max) (@VGS} = 1.8 V)$

: $R_{on} = 0.85 \Omega \text{ (max) (@V_{GS} = 2.5 V)}$

: $R_{on} = 0.66 \Omega \text{ (max)} (@V_{GS} = 4.5 \text{ V})$

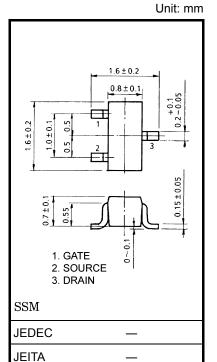
: $R_{on} = 0.63 \Omega \text{ (max) } (@V_{GS} = 5.0 \text{ V})$

Absolute Maximum Ratings (Ta = 25 °C)

Characteristics		Symbol	Rating	Unit	
Drain-source voltage		V_{DS}	20	V	
Gate-source voltage		V _{GSS}	± 10	V	
Drain current	DC	I _D	500	mA	
	Pulse	I _{DP}	1000		
Drain power dissipation		P _D (Note1)	150	mW	
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	

Note1: Mounted on an FR4 board

(25.4 mm \times 25.4 mm \times 1.6 mm, Cu Pad: 0.36 mm² \times 3)

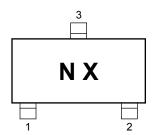


2-2H1B

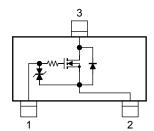
Weight: 2.4 mg (typ.)

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Marking



Equivalent Circuit (top view)

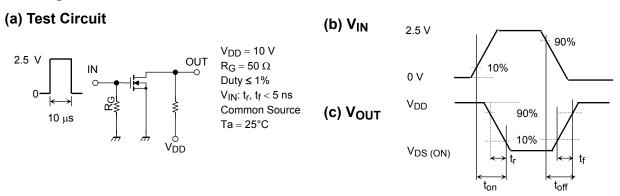


Electrical Characteristics (Ta = 25°C)

Chara	acteristics	Symbol	Test Conditions	Min	Тур.	Max	Unit
Drain-source breakdown voltage	V (BR) DSS	$I_D = 1 \text{ mA}, V_{GS} = 0$	20	_	_	V	
	V (BR) DSX	I _D = 1 mA, V _{GS} = - 10 V	12	_	_	, v	
Drain cutoff current		I _{DSS}	V _{DS} =20 V, V _{GS} = 0	_	_	1	μА
Gate leakage curre	ent	I _{GSS}	$V_{GS} = \pm 10 \text{ V}, V_{DS} = 0$	_	_	±1	μА
Gate threshold vol	tage	V _{th}	$V_{DS} = 3 \text{ V}, I_D = 1 \text{ mA}$	0.35	—	1.0	V
Forward transfer a	dmittance	Y _{fs}	$V_{DS} = 3 \text{ V}, I_D = 200 \text{ mA}$ (Note2)	420	840	_	mS
Drain-source ON-resistance	RDS (ON)	$I_D = 200 \text{ mA}, V_{GS} = 5.0 \text{ V}$ (Note2)	_	0.46	0.63	Ω	
		I _D = 200 mA, V _{GS} = 4.5 V (Note2)	_	0.51	0.66		
		I _D = 200 mA, V _{GS} = 2.5 V (Note2)	_	0.66	0.85		
		I _D = 100 mA, V _{GS} = 1.8 V (Note2)	_	0.81	1.14		
		$I_D = 50 \text{ mA}, V_{GS} = 1.5 \text{ V}$ (Note2)	_	0.95	1.52		
Input capacitance Output capacitance		C _{iss}		_	46	_	pF
		C _{oss}	V _{DS} = 10 V, V _{GS} = 0, f = 1 MHz	_	10.8	_	
Reverse transfer capacitance		C _{rss}		_	7.3	_	
Total Gate Charge Gate-Source Charge		Qg		_	1.23		nC
		Qgs	V_{DS} = 10V, I_{D} = 0.5 A, V_{GS} = 4.0 V	_	0.60		
Gate–Drain Charge		Q _{gd}		_	0.63	_	
Switching time	Turn-on time	t _{on}	V _{DD} = 10 V, I _D = 200 mA	_	30	_	ns
	Turn-off time	t _{off}	$V_{GS} = 0$ to 2.5 V, $R_G = 50 \Omega$	_	75	_	
Drain-source forward voltage		V _{DSF}	$I_D = -0.5 \text{ A}, V_{GS} = 0 \text{ V}$ (Note2)	_	-0.88	-1.2	V

Note2: Pulse test

Switching Time Test Circuit

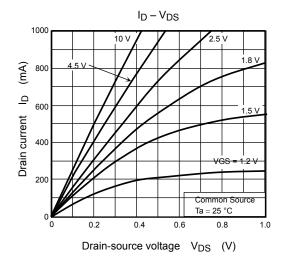


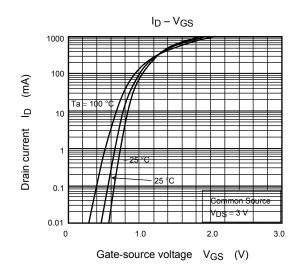
Usage Considerations

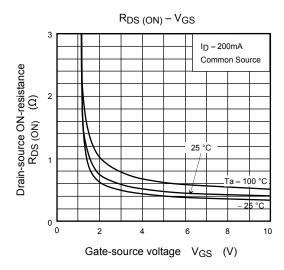
Let V_{th} be the voltage applied between gate and source that causes the drain current (I_D) to below (1 mA for the SSM3K36FS). Then, for normal switching operation, $V_{GS(on)}$ must be higher than V_{th} , and $V_{GS(off)}$ must be lower than V_{th} . This relationship can be expressed as: $V_{GS(off)} < V_{th} < V_{GS(on)}$. Take this into consideration when using the device.

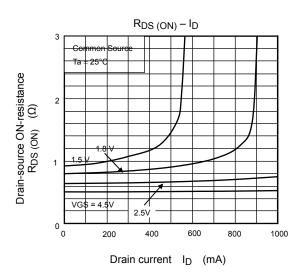
Handling Precaution

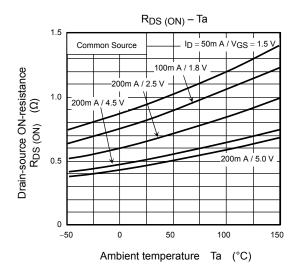
When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

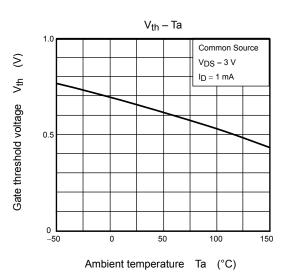


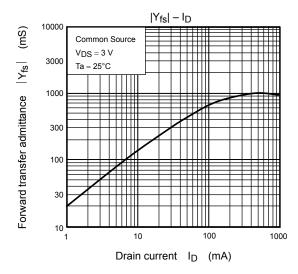


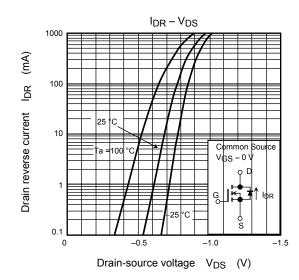


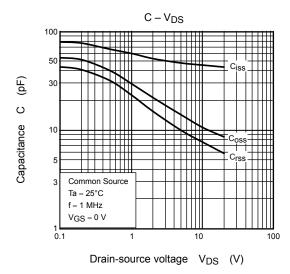


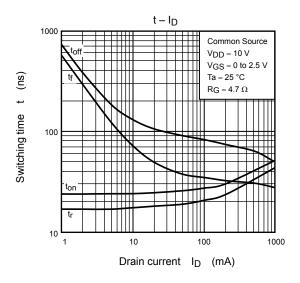


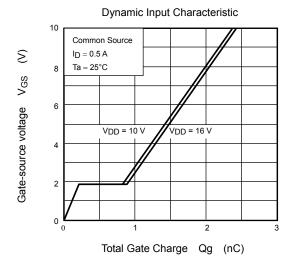


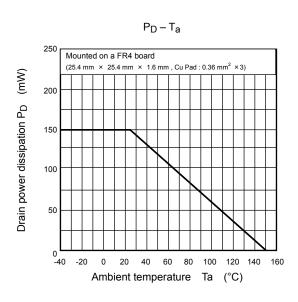












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